



SOT-23



Pin Definition:

1. Gate
2. Source
3. Drain

### PRODUCT SUMMARY

$V_{DS}$ (V)	$R_{DS(on)}$ (m $\Omega$ )	$I_D$ (A)
-30	180 @ $V_{GS} = -10V$	-1.3
	300 @ $V_{GS} = -4.5V$	-1.1

### Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

### Application

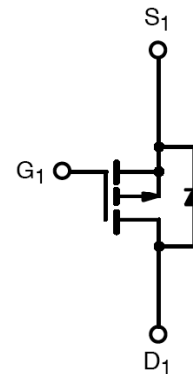
- Portable Devices
- High Speed Switch

### Ordering Information

Part No.	Package	Packing
TSM2303CX RFG	SOT-23	3Kpcs / 7" Reel

Note: "G" denotes Halogen Free Product.

### Block Diagram



P-Channel MOSFET

### Absolute Maximum Rating ( $T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	-1.3	A
Pulsed Drain Current	$I_{DM}$	-10	A
Continuous Source Current (Diode Conduction) <sup>a,b</sup>	$I_S$	-1.3	A
Maximum Power Dissipation	$P_D$	$T_A=25^\circ C$	0.7
		$T_A=75^\circ C$	0.45
Operating Junction Temperature	$T_J$	+150	$^\circ C$
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ C$

### Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	$R_{\theta JC}$	80	$^\circ C/W$
Junction to Ambient Thermal Resistance (PCB mounted)	$R_{\theta JA}$	140	$^\circ C/W$

#### Notes:

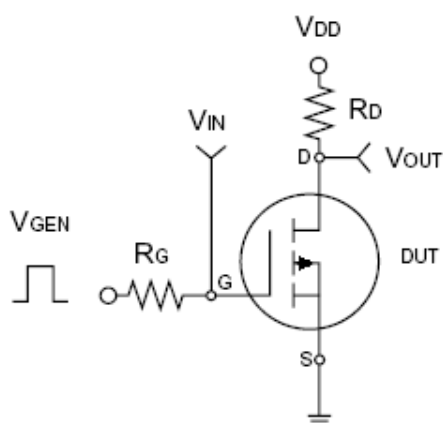
- a. Pulse width limited by the Maximum junction temperature
- b. Surface Mounted on a 1 in<sup>2</sup> pad of 2oz Cu,  $t \leq 5$  sec.

### Electrical Specifications (Ta = 25°C unless otherwise noted)

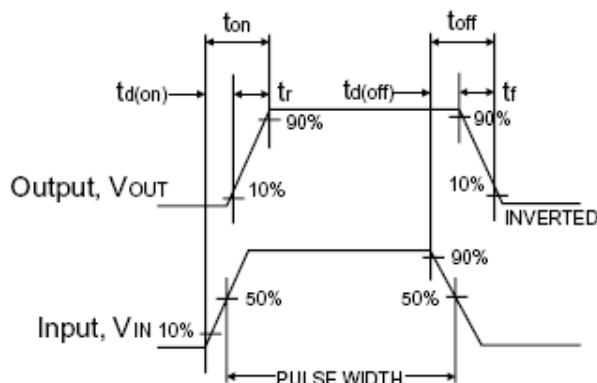
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	$BV_{DSS}$	-30	--	--	V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	$V_{GS(TH)}$	-1	--	-3	V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	$I_{GSS}$	--	--	$\pm 100$	nA
Zero Gate Voltage Drain Current	$V_{DS} = -30V, V_{GS} = 0V$	$I_{DSS}$	--	--	1.0	$\mu A$
Drain-Source On-State Resistance	$V_{GS} = -10V, I_D = -1.3A$	$R_{DS(ON)}$	--	150	180	m $\Omega$
	$V_{GS} = -4.5V, I_D = -1.1A$		--	250	300	
Forward Transconductance <sup>a</sup>	$V_{DS} = -15V, I_D = -1.3A$	$g_{fs}$	--	5	--	S
Diode Forward Voltage	$I_S = -1.3A, V_{GS} = 0V$	$V_{SD}$	--	--	-1.2	V
<b>Dynamic<sup>b</sup></b>						
Total Gate Charge	$V_{DS} = -10V, I_D = -1.3A,$ $V_{GS} = -4.5V$	$Q_g$	--	10	15	nC
Gate-Source Charge		$Q_{gs}$	--	1.9	--	
Gate-Drain Charge		$Q_{gd}$	--	2	--	
Input Capacitance	$V_{DS} = -10V, V_{GS} = 0V,$ $f = 1.0MHz$	$C_{iss}$	--	565	--	pF
Output Capacitance		$C_{oss}$	--	126	--	
Reverse Transfer Capacitance		$C_{rss}$	--	75	--	
<b>Switching<sup>b,c</sup></b>						
Turn-On Delay Time	$V_{DD} = -10V, R_L = 15\Omega,$ $I_D = -1A, V_{GEN} = -4.5V,$ $R_G = 6\Omega$	$t_{d(on)}$	--	10	--	nS
Turn-On Rise Time		$t_r$	--	9	--	
Turn-Off Delay Time		$t_{d(off)}$	--	27	--	
Turn-Off Fall Time		$t_f$	--	7	--	

#### Notes:

- a. pulse test:  $PW \leq 300\mu S$ , duty cycle  $\leq 2\%$
- b. For DESIGN AID ONLY, not subject to production testing.
- c. Switching time is essentially independent of operating temperature.



Switching Test Circuit

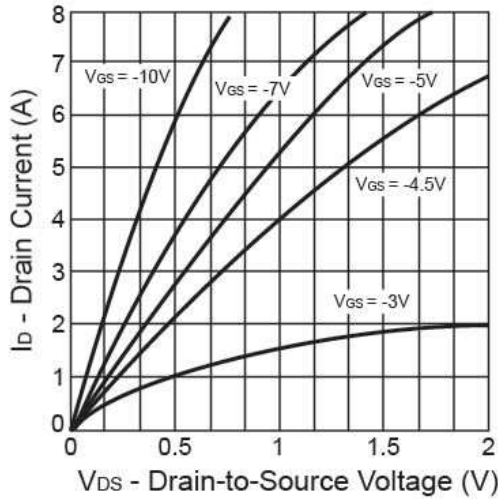


Switchin Waveforms

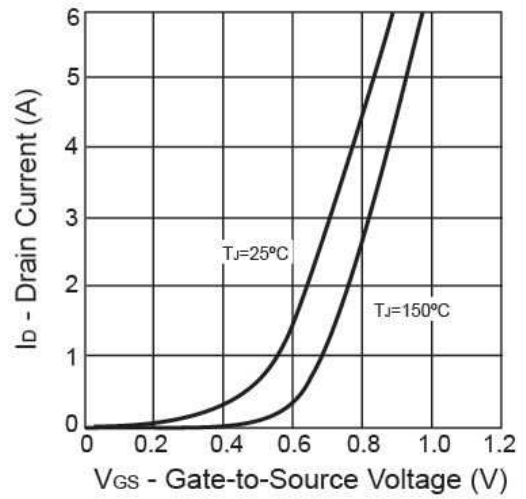


**Electrical Characteristics Curve** (Ta = 25°C, unless otherwise noted)

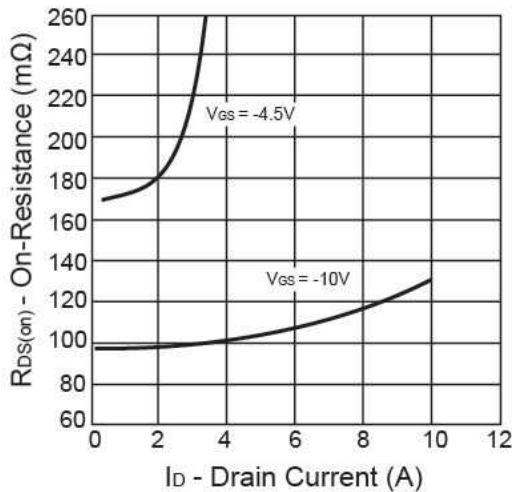
**Output Characteristics**



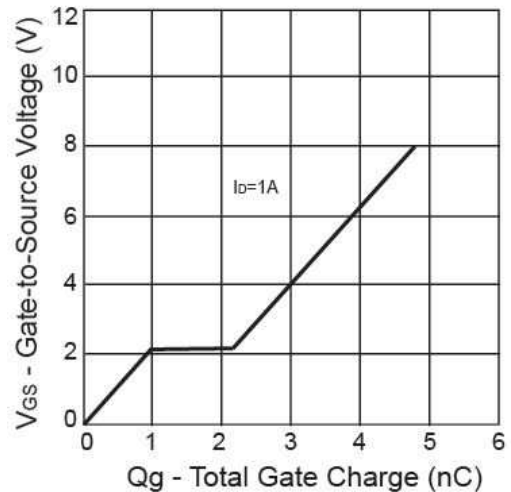
**Transfer Characteristics**



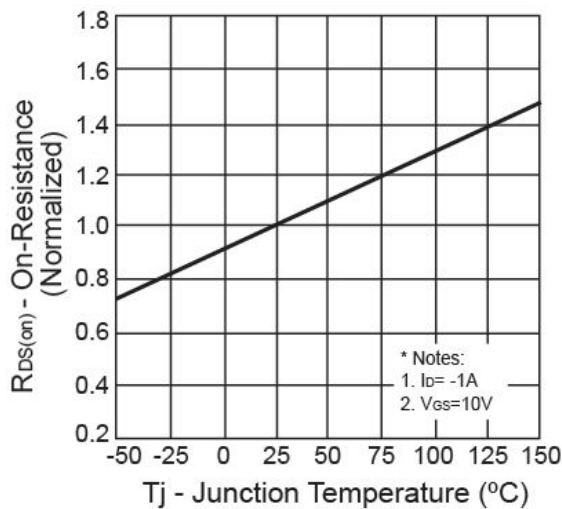
**On-Resistance vs. Drain Current**



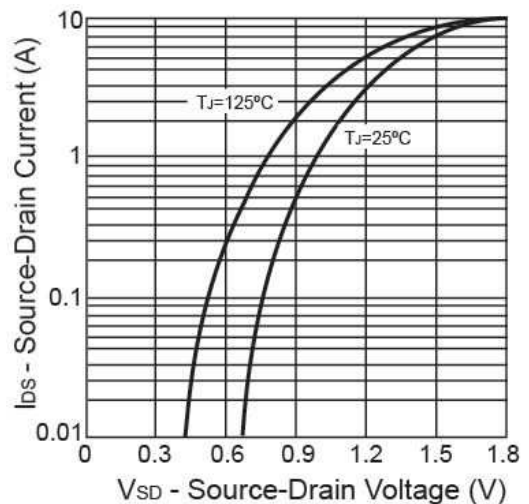
**Gate Charge**



**On-Resistance vs. Junction Temperature**



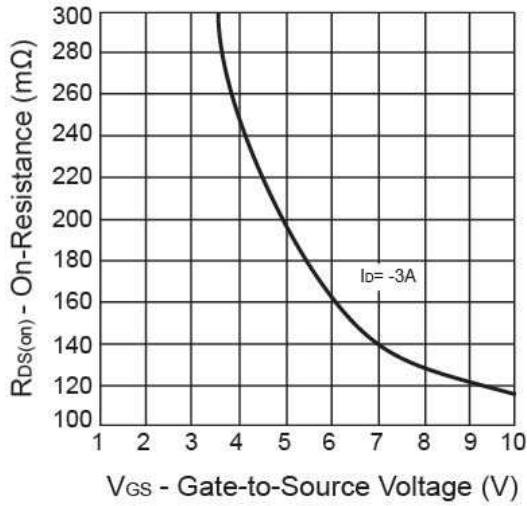
**Source-Drain Diode Forward Voltage**



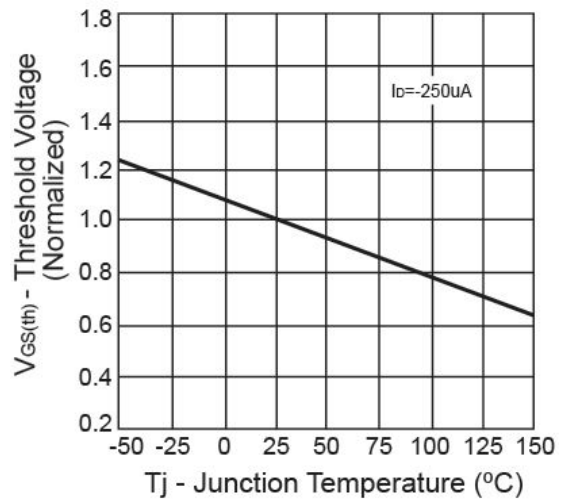


**Electrical Characteristics Curve** (Ta = 25°C, unless otherwise noted)

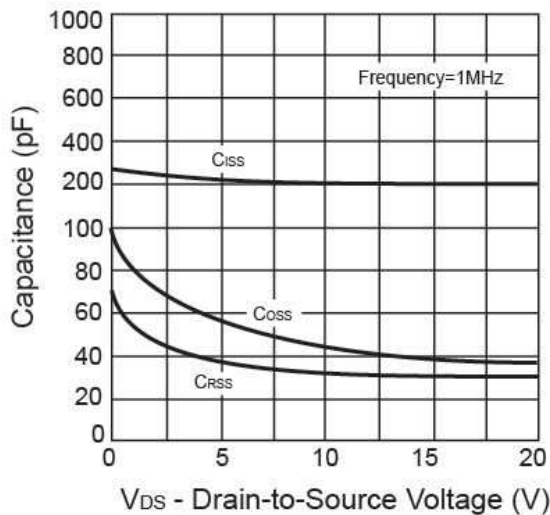
**On-Resistance vs. Gate-Source Voltage**



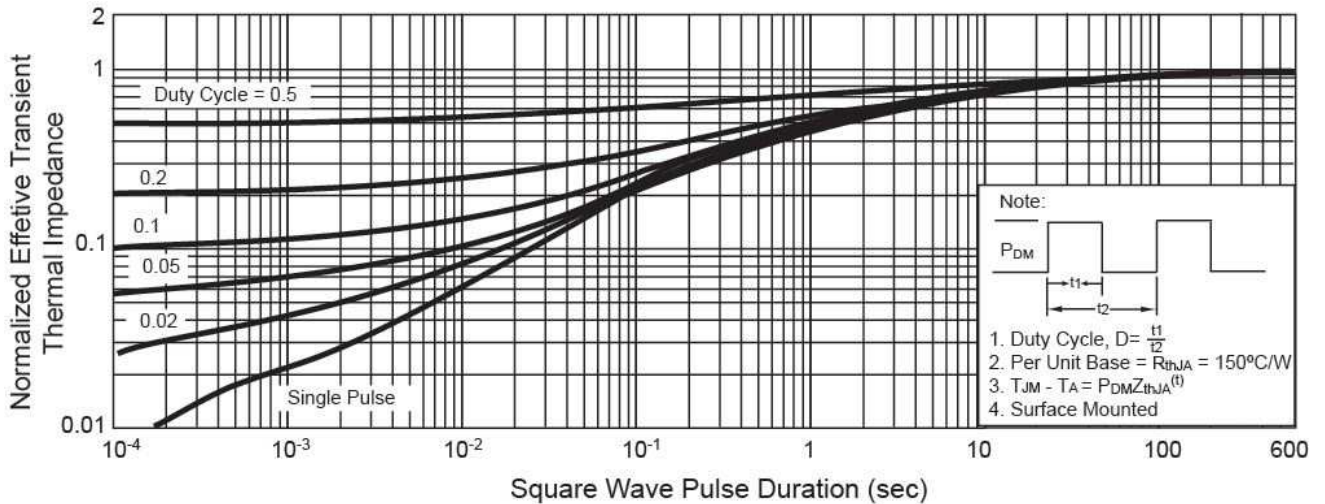
**Threshold Voltage**



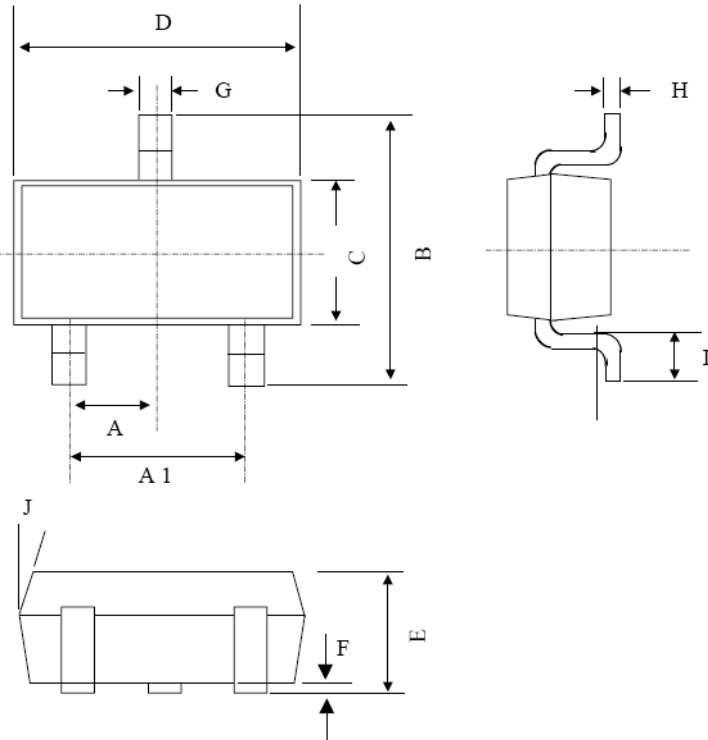
**Capacitance**



**Normalized Thermal Transient Impedance, Junction-to-Ambient**

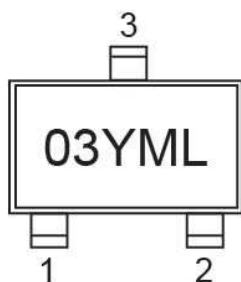


**SOT-23 Mechanical Drawing**



DIM	SOT-23 DIMENSION			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX.
A	0.95 BSC		0.037 BSC	
A1	1.9 BSC		0.074 BSC	
B	2.60	3.00	0.102	0.118
C	1.40	1.70	0.055	0.067
D	2.80	3.10	0.110	0.122
E	1.00	1.30	0.039	0.051
F	0.00	0.10	0.000	0.004
G	0.35	0.50	0.014	0.020
H	0.10	0.20	0.004	0.008
I	0.30	0.60	0.012	0.024
J	5°	10°	5°	10°

**Marking Diagram**



- 03** = Device Code
- Y** = Year Code
- M** = Month Code for Halogen Free Product
  - O** =Jan    **P** =Feb    **Q** =Mar    **R** =Apr
  - S** =May    **T** =Jun    **U** =Jul    **V** =Aug
  - W** =Sep    **X** =Oct    **Y** =Nov    **Z** =Dec
- L** = Lot Code

## Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.